2N5114JAN/JANTX/JANTXV Series

SPECIFICATIONS (T_A = 25° C UNLESS OTHERWISE NOTED)

Vishay Siliconix

Downloaded from Arrow.com.

				Limits							
					2N5114		2N5115		2N5116		1
Parameter	Symbol	Test Co	nditions	Typ ^a	Min	Max	Min	Max	Min	Max	Unit
Static						<u> </u>		<u> </u>		<u> </u>	1
Gate-Source Breakdown Voltage	V _{(BR)GSS}	I_{G} = 1 μA , V_{DS} = 0 V		45	30		30		30		v
Gate-Source Cutoff Voltage	V _{GS(off)}	$V_{DS} = -15 \text{ V}, \text{ I}_{D} = -1 \text{ nA}$			5	10	3	6	1	4	1
Saturation Drain Current ^b	I _{DSS}	V _{GS} = 0 V	$V_{DS} = -18 V$		-30	-90	45			05	mA
			$V_{DS} = -15 V$	5		500	-15	-60 500	-5	-25 500	~ ^
Gate Reverse Current	I _{GSS}	V _{GS} = 20 V	, v _{DS} = 0 v T _A = 150°C	0.01		1		1		1	pΑ μΑ
Gate Operating Current ^c	IG	V _{DG} = -15 V		-5		-		-		-	μΑ
Drain Cutoff Current	'G	V _{DS} = -15 V	V _{GS} = 12 V	-10		-500					рА
			V _{GS} = 7 V	-10				-500			
			V _{GS} = 5 V	-10						-500	
	I _{D(off)}	V _{DS} = -15 V T _A = 150°C	V _{GS} = 12 V	-0.02		-1					μΑ
			V _{GS} = 7 V	-0.02				-1			
			V _{GS} = 5 V	-0.02						-1	
Drain-Source On-Voltage	V _{DS(on)}	V _{GS} = 0 V	I _D = -15 mA	-1.0		-1.3					
			I _D = -7 mA	-0.7				-0.8			V
			I _D = -3 mA	-0.5						-0.6	
Drain-Source On-Resistance	r _{DS(on)}	$V_{GS} = 0 V, I_D = -1 mA$				75		100		150	Ω
Gate-Source Forward Voltage	V _{GS(F)}	$I_{G} = -1 \text{ mA}$, $V_{DS} = 0 \text{ V}$		-0.7		-1		-1		-1	V
Dynamic											
Drain-Source On-Resistance	r _{ds(on)}	$V_{GS} = 0 \text{ V}, I_D = 0 \text{ mA}, f = 1 \text{ kHz}$				75		100		175	Ω
Common-Source Input Capacitance	C _{iss}	V _{DS} = -15 V, V _{GS} = 0 V f = 1 MHz		20		25		25		27	
Common-Source Reverse Transfer Capacitance	C _{rss}	V _{DS} = 0 V f = 1 MHz	V _{GS} = 12 V	5		7					pF
			V _{GS} = 7 V	6				7			
			$V_{GS} = 5 V$	6						7	
Switching											•
Turn-On Time	t _{d(on)}	See Switching Circuit				6		10		25	ns
	t _r					10		20		35	
Turn-Off Time	t _{d(off)}					6		8		20	
	t _f				15		30		60		
Notos	-				-		-	-		-	

Notes
a. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
b. Pulse test: PW ≤ 300 μs duty cycle ≤ 3%.
c. This parameter not registered with JEDEC.

PSCIA





2N5114JAN/JANTX/JANTXV Series

Vishay Siliconix

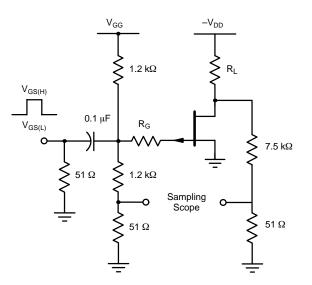
SWITCHING TIME TEST CIRCUIT								
	2N5114	2N5115	2N5116					
V _{DD}	–10 V	-6 V	6 V					
V _{GG}	20 V	12 V	8 V					
R _L *	430 Ω	910 Ω	2000 Ω					
R _G *	100 Ω	220 Ω	390 Ω					
I _{D(on)}	–15 mA	-7 mA	–3 mA					
V _{GS(H)}	0 V	0 V	0 V					
V _{GS(L)}	–11 V	-7 V	–5 V					

*Non-inductive INPUT PULSE

SAMPLING SCOPE

Rise Time < 1 ns Fall Time < 1 ns Pulse Width 100 ns PRF 1 MHz Rise Time 0.4 ns Input Resistance 10 $M\Omega$ Input Capacitance 1.5 pF

See Typical Characteristics curves for changes.





Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.